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[捷配PCB打样工厂, 24小时加急出货](#)

POSEICO

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FAST RECOVERY DIODE

ARF694

FOR IGBT, IEGT, GCT APPLICATIONS

SNUBBERLESS OPERATION

LOW LOSSES SOFT RECOVERY

Repetitive voltage up to

6000 V

Mean forward current

645 A

Surge current

10 kA

TARGET SPECIFICATION

mar 03 - ISSUE : 2

Symbol	Characteristic	Conditions	Tj [°C]	Value	Unit
BLOCKING					
V _{RRM}	Repetitive peak reverse voltage		120	6000	V
V _{RSM}	Non-repetitive peak reverse voltage		120	6100	V
I _{RRM}	Repetitive peak reverse current	V=V _{RRM}	120		mA
V _{DC LINK}	Permanent DC voltage		120	3200	V
CONDUCTING					
I _{F (AV)}	Mean forward current	180° sin ,50 Hz, Th=55°C, double side cooled		645	A
I _{F (AV)}	Mean forward current	180° square, 50 Hz, Th=55°C, double side cooled		675	A
I _{FSM}	Surge forward current	Sine wave, 10 ms	120	10	kA
I ² t	I ² t	reapplied reverse voltage up to 50% VRSM		500 x1E3	A²s
V _{FM}	Forward voltage	Forward current = 1570 A	25	4.8	V
V _{F(TO)}	Threshold voltage		120	2.10	V
r _F	Forward slope resistance		120	1.80	mohm
SWITCHING					
Q _{rr}	Reverse recovery charge	I _F = 1000 A di/dt= 250 A/μs V _R = 100 V	120		μC
I _{rr}	Peak reverse recovery current		120		A
t _{rr}	Reverse recovery time	I _F = 1000 A	120		μs
Q _{rr}	Reverse recovery charge	di/dt= 500 A/μs V _R = V		2000	μC
I _{rr}	Peak reverse recovery current			1150	A
s	Softness (s-factor), min				
E _{OFF}	Turn off energy dissipation				J
V _{FR}	Peak forward recovery	di/dt= 500 A/μs	125		V
MOUNTING					
R _{th(j-h)}	Thermal impedance	Junction to heatsink, double side cooled		21	°C/kW
R _{th(c-h)}	Thermal impedance	Case to heatsink, double side cooled		3	°C/kW
T _j	Operating junction temperature			-30 / 120	°C
F	Mounting force			22.0 / 24.5	kN
Mass				520	g

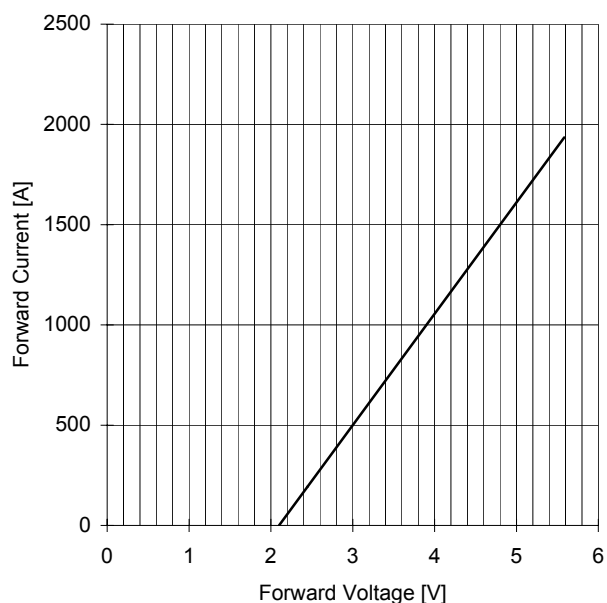
ORDERING INFORMATION : ARF694 S 60

ARF694 FAST RECOVERY DIODE

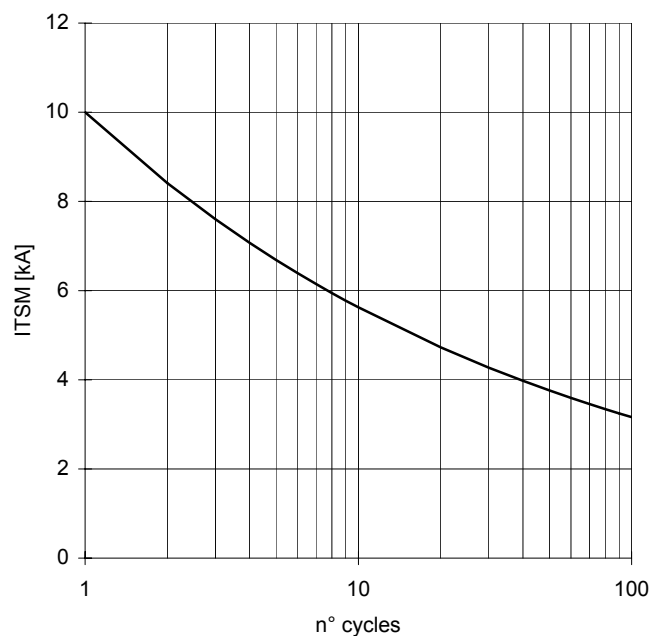


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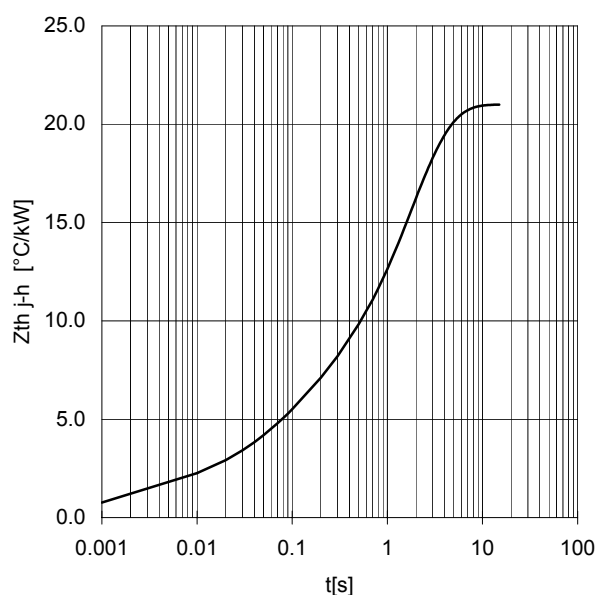
FORWARD CHARACTERISTIC
 $T_j = 120^\circ\text{C}$



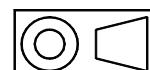
SURGE CHARACTERISTIC
 $T_j = 120^\circ\text{C}$



TRANSIENT THERMAL IMPEDANCE
DOUBLE SIDE COOLED



Dimensions
in mm



All the characteristics given in this data sheet are guaranteed only with uniform clamping force, cleaned and lubricated heatsink, surfaces with flatness $< .03\text{ mm}$ and roughness $< 2\text{ }\mu\text{m}$.

In the interest of product improvement POSEICO SpA reserves the right to change any data given in this data sheet at any time without previous notice.

If not stated otherwise the maximum value of ratings (symbols over shaded background) and characteristics is reported.

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